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Skyrmion Dynamics for Spintronic Devices

A Thesis submitted in partial satisfaction
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in

Electrical Engineering

by

Yizhou Liu

December 2013

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Magnetic Skyrmion is a topological stable, particle-like spin texture. Its unique properties such as current-driven motion and topological protected make it to be a candidate for future spintronic devices. However, Skyrmion dynamics are still not that clear to build real devices. To investigate those Skyrmion dynamics, a code was developed to solving the Landau-Lifshitz-Gilbert Equation. Skyrmion dynamics with spin waves is investigated by micromagnetic simulations, we find that the scattering angle of the spin wave is related to the size of Skyrmion. We also show the simulation of the topological hall effect that maybe used to read a Skyrmion. Based on the current dynamic properties of Skyrmion, we proposed a Skyrmion-based architecture.
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Chapter 1

Motivation

In recent years, electronic devices such as CPU and memory get faster and smaller. However, the speed improvement seems not that obviously compare to 10 years before. The silicon-based electronic devices are almost reach their physical limit. The scale of these devices is a problem when the size is down to sub-10nm, there will be quantum effect that is hard to control. So more and more researchers are now focusing on finding new pathway to build next generation devices. There are some candidates for next generation devices such as the magnetic-tunneling junction[6], domain wall race-track memory[5], carbon nanotube(CNT) based computing unit[7] and also the quantum computing[8]. So it’s really necessary to find a new candidate technology to get over the current bottleneck in electronic devices.

Magnetic Skyrmion, which is a topological protected spin texture, gains a lot of interest in recent years. It has some unique properties such as the particle like behavior, current-driven motion[9]. And since it’s topological protected, a defect cannot stop the motion of Skyrmion[10]. It’s also known that we can control the Skyrmion motion by a electric field in a insulator, which maybe a solution for making devices
without joule heat [1]. But there are still some open questions of its properties need to be solved, especially the dynamics behavior, before we build real Skyrmion-based devices. So inspired by these open questions, we investigate some Skyrmion dynamics by micromagnetic simulations and propose some possible architectures for Skyrmion-based spintronic devices.
Chapter 2

Magnetism

Since magnetic Skyrmion is a topological protected spin texture, the origin of Skyrmion should be the magnetism. Magnetism has been known for such a long time by human beings. However, after entering the 20th century, there is more researches on the micromagnetism and the quantum theory of magnetism. So to understand the physics of magnetic Skyrmion I want to introduce some concepts of magnetism first in this chapter.

2.1 Bohr Magneton and Magnetic Moment

Bohr model in atomic physics was introduced by Niels Bohr in 1913. The emergence of Bohr model gives physicist a rational picture of the atom structure. In this picture, the electron in a hydrogen atom with mass $m$ and charge $-e$ (which $e$ is the proton charge). The electrostatic force on the electron should equal to the centripetal force to hold the electron in its circular orbit with a radius $r$, as shown in Eq. (2.1):

$$\frac{e^2}{4\pi\varepsilon_0 r} = \frac{mv^2}{r} \quad (2.1)$$
Bohr model proposed that the electron can only stay in one of a number of discrete orbits to keep orbit stably without radiating. Then we will have the assumption in Eq. (2.2)

\[ mvr = n\hbar \]  

(2.2)

with \( n = 1, 2, 3, \ldots \), where \( \hbar \) is the reduced Planck’s constant. By Eq. (2.1) and Eq. (2.2), we can eliminate \( v \) to obtain \( r \) and then find the total energy:

\[ r = n^2 \frac{4\pi\varepsilon_0 \hbar^2}{me^2} = n^2 a_0, \quad E_n = -\frac{1}{n^2} \frac{e^4 m}{2(4\pi\varepsilon_0)^2 \hbar^2} \]  

(2.3)

\( a_0 = 0.5292 \times 10^{-10} \text{ m} \) is the well known Bohr radius. The energy gap between two neighbor orbits is \( hf = E_1 - E_2 \), which \( f \) is the frequency and \( E_1, E_2 \) are two energy states associate with these two orbits.

![Illustration of a magnetic moment and its current loop.](image)

Figure 2.1: Illustration of a magnetic moment and its current loop.

The classical expression of a magnetic moment for an electron is \( \mu = IA \). The effective current induced by this electron can be written as \( I = -\frac{e}{T} \), where \( T = \frac{2\pi}{v} \) is the period of orbit. Using the equations above we obtain

\[ \mu_B = \frac{|e| \hbar}{2m} \]  

(2.4)

\( \mu_B = 9.2740 \times 10^{-24} \text{ J/T} \) is a unit of magnetic moment so called the Bohr magneton.
Furthermore we can show that the ratio

\[ \frac{\mu}{L} = \gamma = -\frac{e}{2m} \]  (2.5)

between magnetic moment \( \mu \) and angular momentum \( L \) depends only on basic constants. This ratio, \( \gamma \), is called the gyromagnetic ratio, and will be used in the later chapters.

2.2 Magnetic Interaction

Magnetic structures such as domain wall, magnetic vortex could be found in magnets and used for applications. To study these magnetic structures we need to understand the origin of a magnetic structure or a magnetic phenomena. The theory of micromagnetism is still unknown until the early 20th century. After the discovery of electrons and the foundation of quantum theory, it became possible to describe these magnetic structures clearly by magnetic interaction and gave us a vision into the origin of micromagnetism.

2.2.1 Heisenberg Exchange Interaction

The Heisenberg exchange is rising from the interaction between two electrons. Consider a simple case that two electrons with different spatial coordinates \( r_1 \) and \( r_2 \). The coupling of the two electrons will give a rise to the Hamiltonian that can be written as:

\[ H = J \cdot \mathbf{S}_i \cdot \mathbf{S}_j \]  (2.6)

where \( \mathbf{S}_i \) and \( \mathbf{S}_j \) are the spin operators of these two electrons. Since electron has a spin \( \frac{1}{2} \), the total spin of this system \( \mathbf{S}_{tot} = \mathbf{S}_i + \mathbf{S}_j \) has an eigenvalue of either 0 or 1. Then we can have

\[ (\mathbf{S}_{tot})^2 = (\mathbf{S}_i)^2 + (\mathbf{S}_j)^2 + 2 \cdot \mathbf{S}_i \cdot \mathbf{S}_j \]  (2.7)
the eigenvalue of \((S_{tot})^2\) could be either 0 or 2 for spin 0 or 1 respectively. Because we know the eigenvalue of \((S_i)^2\) and \((S_j)^2\) are both \(\frac{3}{4}\), we can easily obtain \(S_i \cdot S_j\) by Eq. (2.7)

\[
S_i \cdot S_j = \begin{cases} 
\frac{1}{4} & \text{for } s = 1 \\
-\frac{3}{4} & \text{for } s = 0 
\end{cases}
\] (2.8)

take those values back to Eq. 2.6, the eigenvalues of the Hamiltonian are

\[
E = \begin{cases} 
\frac{J}{4} & \text{for } s = 1 \\
-\frac{3J}{4} & \text{for } s = 0 
\end{cases}
\] (2.9)

The degeneracy of each state can be given by \(2s + 1\), so the \(s = 0\) state is the singlet state and the \(s = 1\) state is the triplet state. Hence we can write the wavefunction of these two states as

\[
\Psi_S = \frac{1}{\sqrt{2}} [\phi_i(r_1)\phi_j(r_2) + \phi_i(r_2)\phi_j(r_1)] \chi_S \\
\Psi_T = \frac{1}{\sqrt{2}} [\phi_i(r_1)\phi_j(r_2) - \phi_i(r_2)\phi_j(r_1)] \chi_T
\] (2.10)

and the energy difference between these two states is

\[
E_S - E_T = 2 \int \phi_i^*(r_1)\phi_j^*(r_2)H\phi_i(r_2)\phi_j(r_1)dr_1dr_2
\] (2.11)

We define the exchange constant \(J\) as

\[
J = \frac{E_S - E_T}{2} = \int \phi_i^*(r_1)\phi_j^*(r_2)H\phi_i(r_2)\phi_j(r_1)dr_1dr_2
\] (2.12)

Hence the Hamiltonian can be finally written as

\[
H = -2J \cdot S_i \cdot S_j
\] (2.13)

If \(J > 0\), \(E_S > E_T\) means the triplet state\((S = 0)\) is in lower energy and the neighbour spins intend to be parallelized each other to form the ferromagnetic\(\text{FM}\). If \(J < 0\), \(E_S < E_T\) means the singlet state\((S = 1)\) is in lower energy and the neighbour spins intend to
be antiparallelized each other to form the antiferromagnetic (AFM). Furthermore, Eq. (2.13) can be written in a more general way

\[ H = -\sum_{i,j} J_{ij} S_i \cdot S_j \]

where \( J_{ij} \) is the exchange constant between two sites \( i \) and \( j \). This form is usually used in solid state physics and so called the classical Heisenberg model.

### 2.2.2 Dzyaloshinskii-Moriya Interaction

The interaction due the broken of symmetry is called the Dzyaloshinskii-Moriya interaction\[11, 12\]. Due to the observation of some complex, non-linear spin textures, the DM interaction becomes more and more important in the comparison of material properties. The DM interaction was first proposed by I. Dzyaloshinskii in 1958 and T. Moriya generalized this theory two years later. By Moriya’s theory we could determine the direction of the DM interaction. A normal expression of a DM interaction is

\[ H = D_{12} \cdot (S_1 \times S_2) \]

where \( D \) is the DM constant. Under the inversion operation, two spins \( S_1 \) and \( S_2 \) are exchanged. The cross product reverses the sign of the Hamiltonian. The DM interaction is the key factor to generate a Skyrmion and we will discuss it in details in the following chapters.
2.3 Zeeman Energy

Magnetic structure is not only the result of magnetic interactions, but also the result of external applied field. The interaction of an atom with a magnetic field is called the Zeeman energy. It's caused by the spin of the electrons in an atom. The Zeeman energy is given by:

\[ H = -h_0 \cdot m \]  

(2.15)

where \( h_0 \) is the external field and \( m \) is the magnetic moment.
Chapter 3

Magnetic Skyrmion

In 1962, Tony Skyrme proposed that protons and neutrons exist as topological solitons[13]. These solitons are particle-like field configurations. And since they are topologically protected, their structures are stable and cannot be deformed continuously. This concept is applied in many fields such as particle physics and condensed-matter physics, and this kind of solitons is called Skyrmion.

3.1 Magnetic Skyrmion

Magnetic skyrmions are topologically protected, particle-like spin textures. They range in sizes from 10 nm to approximately 100 nm depending on material parameters. They can be created and annihilated by spin currents and magnetic fields, and they can be easily moved by an electrical current [14, 10]. In many materials, skyrmions are the middle phase of a progression of three phases with increasing magnetic field: helical, skyrmion, and ferromagnetic [15]. Because of their small size, their stability, the demonstration of their individual creation and annihilation, and their facile movement with low current, they are being investigated for information storage (memory)
The origin of a magnetic Skyrmion is the Dzyaloshinskii-Moriya interaction and its competition with other magnetic interactions such as the exchange interaction. The Dzyaloshinskii-Moriya interaction $H = D_{12} \cdot (S_1 \times S_2)$ comes from inversion symmetry breaking and spin-orbit interaction. Under the inversion operation, two spins $S_1$ and $S_2$ are exchanged. The cross product reverses the sign of the Hamiltonian. Up to now, most bulk materials for Skyrmion crystal belong to the category of B20 compounds, whose space group is $P2_13$. Although they are cubic lattices, the symmetry is very low due to the complicated structures inside each unit cell. The inversion symmetry is missing consequently. Another route to the Dzyaloshinskii-Moriya interaction is to grow magnetic thin films on certain substrates. The inversion symmetry is apparently
broken due to different chemical environments above and below that thin film. On the other hand, the amplitude of the Dzyaloshinskii-Moriya interaction is proportional to the strength of spin-orbit interaction. Therefore it is better to use materials with large spin-orbit interaction as the substrate.

3.2 Skyrmion Lattice

The first magnetic Skyrmion was observed in MnSi which is a phase between the helical state and ferromagnetic state. By the presence of a finite external field, a Skyrmion phase will be generated. The Skyrmions were arranged as a hexagonal like lattice on the plane perpendicular to the external field.

The phase diagram of MnSi bulk sample is shown in Fig. 3.3. At low temperature, when the magnetic field is high enough, local spins are fully polarized so that ferromagnetic order is respected. When the magnetic field is reduce, the conical phase is energetically favored. In this phase, the spins are propagating in the $\hat{z}$ direction and rotating about the $z$ axis like an umbrella. The net magnetization is nonzero so that energy can still be saved from the Zeeman coupling. This phase is the result of compro-
mise between Zeeman interaction and Dzyaloshinskii-Moriya interaction. Furthermore, once the magnetic field is sufficiently small, Zeeman coupling is no longer relevant, and the competition between ferromagnetic exchange and Dzyaloshinskii-Moriya interaction is important. As a result, the helical phase has the lowest energy. In this phase, the spins are coplanar and can propagate in any direction.

The Skyrmion crystal phase (SkX), the so-called A phase in previous literatures, is present at finite temperature. Compared to the conical phase, the free energy of the Skyrmion crystal phase can be reduced due to thermal fluctuations. Mühlbauer et al. performed a neutron scattering analysis of this phase[15]. They found six bright spots forming a hexagon in the momentum space. More importantly, the separation between the bright spots and the Γ point is much smaller than the Brillions zone boundary of the original lattice. All these signals indicate that the Skyrmions form a triangle lattice in this phase.

![Figure 3.3: A Phase diagram of MnSi][2]
In order to further confirm the Skyrmion phase by real space imaging, Fe\textsubscript{0.5}Co\textsubscript{0.5}Si thin film is studied by means of Lorentz Transmission Electron Microscopy\cite{16}. In contrast to the bulk sample, the conical phase is no longer present due to the geometric confinement in the direction perpendicular to the thin film. In this case, Skyrmions can survive down to zero temperature. The Skyrmion crystal phase is really the groundstate of the spin system as long as the magnetic field is properly chosen.

Around the boundary between ferromagnetic phase and the Skyrmion phase, Yu et al. observed the coexistence of both phases\cite{16}. The Skyrmion crystal is melted and single Skyrmion can be observed. This phenomenon shows similarity to the solid-liquid phase transition and indicates the transition from ferromagnetic phase to the Skyrmion crystal phase is first order. The same behavior appears at the transition between the helical phase and the Skyrmion crystals phase. Therefore this phase is first order as well.

All these properties of helimagnet thin film can be captured by the following simple Hamiltonian on two dimensional square lattice\cite{17, 16}. The magnetic orders of this Hamiltonian are simply stacked along the direction perpendicular to the film.

\[
H = \sum_{\langle ij \rangle} \left[ -J S_i \cdot S_j + D_{ij} \cdot (S_i \times S_j) \right] - \sum_i H \cdot S_i \tag{3.1}
\]

where the first term is the Heisenberg ferromagnetic exchange, the second term is the Dzyaloshinskii-Moriya interaction, and the last term is the Zeeman coupling between magnetic moments \( S_i \) and the external magnetic field \( H \). Here the Dzyaloshinskii-Moriya vector \( D_{ij} \) is chosen, due to the lattice symmetry, to be \( D\hat{r}_{ij} \), where the scalar \( D \) describes the interaction strength, and \( \hat{r}_{ij} \) is the unit vector pointing from site \( i \) to site \( j \). All other anisotropy terms and dipolar-dipolar interaction are negligible in the usual cases with small \( D \), the Skyrmion radius or helical period is proportional to \((J/D)a\),
where $a$ is the lattice constant, and the critical field separating the ferromagnetic phase and Skyrmion phase is about $D^2/J\mu_B[17]$. Usually, the Skyrmion radius ranges from 10 to 100nm, and the critical field ranges from 100 to 1000G. It provides the possibility of realizing ultradense and low-dissipative memory devices.

Recently, the magnetic Skyrmion also has been observed in a multiferroic material $Cu_2OSeO_3$, which is also a insulator[1]. $Cu_2OSeO_3$ is also a B20 material that lack the center symmetric of inversion. The crystal structure of a $Cu_2OSeO_3$ is shown in Fig. 3.4 Since this material is an insulator, we can use electric field instead of a electric current to manipulate the Skyrmion and without losses due to the joule heating.

![Figure 3.4: Crystal structure of $Cu_2OSeO_3$, [1]](image-url)
3.3 Skyrmion Dynamics

Skyrmion can be driven by a current or a electrical field in a insulator. Another interesting dynamics property is that a defect cannot stop the motion of a Skyrmion[10]. This property maybe useful when modify Skyrmion in a real devices. The current density need to move a Skyrmion is just about $10^6$ A/m which is 5 orders small than moving a domain wall. That’s one reason why people are really interested in Skyrmion. As shown in Fig. 3.5 When a conduction electron passes through a Skyrmion, its spin is fully polarized by the spin texture which generates a Berry phase that effectively corresponds to a flux quanta, $\phi = h/e$.[18, 16, 19, 3, 20]. This so-called “emergent gauge field” produces a Magnus force perpendicular to the skyrmion velocity as shown in Fig. 3.6, which eventually generates a topological Hall effect. For FeGe, the Skyrmion radius $R$ is about 20nm[21, 22]. The corresponding average emergent magnetic field $b \sim h/e\pi R^2 \approx 3.5T$. For the atomic scale Skyrmion Fe/Ir(111)[23], the average field can

![Figure 3.5: Plot of Skyrmion velocity vs current density.][3]
be as large as several hundred Tesla. Skyrmion crystal automatically provides a high magnetic field laboratory.

Such a high, effective magnetic field naturally results in a Hall effect of the itinerant electrons. However, this topological Hall effect depends on the validity of the adiabatic approximation. When the conduction electron’s kinetic energy is comparable to its exchange coupling to the magnetic moments, perfect alignment between the electron spin and the magnetic moment is no longer the case. Furthermore, a hopping electron provides spin transfer torque, to the magnetic moment.
Chapter 4

Skyrmion dynamic simulation

Since Skyrmion is a topological protected spin texture, its dynamic properties are worth to investigate. Also if we want to make Skyrmion-based devices, it’s necessary to know these kind of properties such as the formation process of a single Skyrmion, current-driven motion, etc. In this chapter, we will discuss the Skyrmion dynamics by micromagnetic simulations.

4.1 Theoretical Background

To investigate the dynamics of Skyrmion, we need to employ the Landau-Lifshitz-Gilbert Equation in our code. The standard expression of a Landau-Lifshitz-Gilbert Equation can be written as:

\[ \dot{S} = -\gamma S \times H_{eff} + \alpha S \times \dot{S} \]  \hspace{1cm} (4.1)

where \( S \) is the magnetization, also known as magnetic moment per unit volume, The magnitude of the spin \( S \) is normalized to unity. \( \alpha \) is the Gilbert damping constant, \( \gamma \) is the gyromagnetic ratio and \( H_{eff}(= -\partial H/\partial S) \) is the effective field acting on the local magnetic moment \( S \). The in-plane magnetic field is included in this effective field.
Starting from a ferromagnetic initial state, we will apply the fourth order Runge-Kutta method to numerically integrate this first differential equation.

Furthermore, if we want to simulating the creation of a single Skyrmion, it is also important to discuss the effect of finite temperatures. Because to create a single Skyrmion, a typical method is applied a current which will generally heat the whole system. To this end, a stochastic Landau-Lifshitz-Gilbert approach will be employed. The equation of motion is given by

\[ \dot{S} = -\gamma S \times (H_{\text{eff}} + L) + \alpha S \times \dot{S} \]  

(4.2)

where \( L \) is a random field characterizing the thermal fluctuation of finite temperature. Although the thermal average of \( L(r, t) \) is zero, the correlation is nonvanishing, satisfying the fluctuation-dissipation relation

\[ \langle L^i(r, t)L^j(r', t') \rangle = \frac{\alpha k_B T}{\gamma} \delta_{ij} \delta_{rr'} \delta_{tt'} \]  

(4.3)

This nonzero correlation guarantees the corresponding thermal equilibrium satisfies the Boltzmann distribution. We can numerically integrate this equation of motion by the means of stochastic integral, and study the effects of finite temperature.

In our simulations, we generalized all parameters in the unit of energy. Then we set \( J = 1, D = 0.3, \) the external field \( H = 0.08. \)

Furthermore, we also develop two different methods to plot the Skyrmion dynamics. One is the color plot, it plots only z component of the magnetization. The other one is the vector plot, it plots the in plane component by arrows and different color to illustrate the direction and value of the magnetization. As shown in Fig. 4.1, we just choose some random places to plot the Skyrmion, on the color plot we have Skyrmion that all spins point up at the edge of it and spin points down at the center. And on the
4.2 Skyrmion Dynamics Simulation

4.2.1 Skyrmion Dynamics with Spinwave

We use open boundary condition in this case to simulate the spin waves or magnons behavior in the presence of Skyrmion. The rectangle shape on the left represents the contact that without a DM interaction. At first we have a Skyrmion in the middle, and then we make a small perturbation at the left edge of the contact, the amplitude $A = < s_x + s_y > = 0.06$. This small perturbation will generate a spin wave propagate to the right. We set the damping constant to 0.0001 to avoid an attenuation of the spin wave. After the spin wave hit the Skyrmion position, there’s an obviously scattering happened as shown in Fig. 4.2. In the case without a Skyrmion, the spin wave just propagate straight to the right.
However, the scattering angle is not a constant. After test different pairs of parameters, the angle seems strongly dependent on the size $R$ of Skyrmion, where $R$ is depend on $\frac{J}{D}$. A plot of different scattering angles with different size of Skyrmion are shown in Fig. 4.3.

### 4.2.2 Topological Hall Effect Simulation

A Skyrmion Topological Hall effect numerical simulation is shown in Fig4.4. The Topological Hall Effect is induced by the conduction electrons go through a Skyrmion, the electron will pick up a Berry phase and influenced by the effective field that generated by the Skyrmion. When an electron system is coupled to the spin system, the electron spin and the on-site local spin are coupled via Hund’s rule coupling:

$$H_{eS} = -J_H \sum_i c_i^\dagger \sigma c_i \cdot S_i.$$  \hfill (4.4)
To couple the spin texture \( \{ S_i \} \) with a tight-binding model, the Hamiltonian of the electron system is

\[
H = \sum_i \epsilon_i c_i^\dagger c_i - t \sum_{\langle i,j \rangle} (c_i^\dagger c_j + \text{h.c.}) - J_H \sum_i c_i^\dagger \sigma c_i \cdot S_i
\]  

(4.5)

Since these are metallic systems, we formulate and obtain a linear response solution to the standard non-equilibrium Green function (NEGF) equations. For horizontal current injection and extraction, open system boundary conditions are applied at the right and left of the tight-binding mesh. Vertical injection can be modeled with boundary conditions previously applied to injection into the surface of a topological insulator. For the contacts at the left and right, the retarded Green function is

\[
G^R = [\epsilon - H - \Sigma_L - \Sigma_R]^{-1}
\]

where \( \Sigma_{L,R} \) stands for the self-energy terms given by the left and right semi-infinite open boundaries. Using the recursive Green function algorithm, one can obtain the diagonal blocks, \( G^R_{n,n} \), and the first column, \( G^R_{n,1} \), respectively. Thus, the left-injected spectral
function can be given as

$$A_{n,n}^L = G_{n,n}^R \Gamma_{1,1} G_{1,n}^{R\dagger}$$  \hspace{1cm} (4.6)$$

in which each on-site block is a $2 \times 2$ matrix in the spin basis. The total spectral function is given as

$$A_{n,n} = A_{n,n}^L + A_{n,n}^R = i \left( G_{n,n}^R - G_{n,n}^A \right)$$  \hspace{1cm} (4.7)$$

where $G^A = G^{R\dagger}$ is the advanced Green’s function. In the linear-response limit, small bias is applied, so the Fermi distribution of the left electrode, $f_L$, and the right electrode, $f_R$ can be expanded to first order in the bias $\mu$,

$$f_L = f_0 + \left( \frac{-\partial f_0}{\partial \epsilon} \right) \frac{\Delta \mu}{2}$$  \hspace{1cm} (4.8)$$

$$f_R = f_0 - \left( \frac{-\partial f_0}{\partial \epsilon} \right) \frac{\Delta \mu}{2}.$$  \hspace{1cm} (4.9)$$

Thus, the lesser Green’s function can be simplified to

$$G_{n,n}^L = i f_L A_{n,n}^L + i f_R A_{n,n}^R = i f_0 A_{n,n} - \frac{\Delta \mu}{2} \left( \frac{\partial f_0}{\partial \epsilon} \right) \left( 2A_{n,n}^L - A_{n,n}^R \right).$$  \hspace{1cm} (4.10)$$

The local charge density can be written as

$$n_{n,n} = n_{n,n}^0 + \Delta n_{n,n} = -i \int \frac{d\epsilon}{2\pi} \text{Tr} \{ G_{n,n}^L (\epsilon) \}$$  \hspace{1cm} (4.11)$$

where

$$\Delta n_{n,n} = \int \frac{d\epsilon}{2\pi} \left( 2A_{n,n}^L - A_{n,n}^R \right) \left( \frac{-\partial f_0}{\partial \epsilon} \right) \frac{\Delta \mu}{2}.$$  \hspace{1cm} (4.12)$$

At equilibrium, the linear response of the charge to a small shift in the local chemical potential, $\delta \mu_{n,n}$, is

$$\Delta n_{n,n} = \int \frac{d\epsilon}{2\pi} A_{n,n} \left( \frac{-\partial f_0}{\partial \epsilon} \right) \delta \mu_{n,n}.$$  \hspace{1cm} (4.13)$$

Comparing Eq. 4.12 and Eq. 4.13, the local non-equilibrium chemical potential is

$$\delta \mu_{n,n} = \frac{\Delta n_{n,n}}{\int \frac{d\epsilon}{2\pi} A_{n,n} \left( \frac{-\partial f_0}{\partial \epsilon} \right)}.$$  \hspace{1cm} (4.14)$$
Letting $t = 1.5 \text{ eV}$, $J_H = 1.0 \text{ eV}$, $T = 300 \text{ K}$, $\Delta \mu = 0.1 \text{ V}$, a numerical simulation of the topological Hall voltage is shown in Fig. 4.4. This is the first such explicit, numerical simulation of the topological Hall effect resulting from a Skyrmion. The transverse difference in the chemical potential is clear in Fig. 4.4(b). This difference in chemical potential is the Hall voltage that is measured in a 4-point probe measurement. By the Topological Hall Effect, the reading of a Skyrmion is possible.

Figure 4.4: Topological Hall effect close to a single skyrmion. In this simulation, the nearest neighbor coupling term is $t = 1.5J_H$, $J_H = 1.0 \text{ eV}$, and $T = 300 \text{ K}$. A voltage drop of $0.1 \text{ V}$ is applied from the left to the right. Close to the skyrmion texture, the transverse chemical potential demonstrates a Hall voltage signal of $0.03 \text{ V}$. 
4.3 Skyrmion-based Device Architecture

Since the simulation shows some interesting properties of Skyrmion, it’s possible for us to propose some Skyrmion-based devices. A very unique property of Skyrmion is the threshold current needed to move a Skyrmion is about 5 orders small compared to the domain wall motion. Inspired by the domain wall racetrack memory[5], a Skyrmion-based racetrack memory is proposed. The advantage of a racetrack memory is we can make 3D architecture as shown in Fig. 4.5 E, so the density can be increased. And since Skyrmion has relatively small size usually range from 10nm to 100nm, we can make devices with higher density. Also, due to the small critical current, this kind of device will be more energy efficient. A schematic structure of Skyrmion-based racetrack memory is shown in Fig. 4.6. We replace the domain wall with Skyrmion arrays. A write head and read head is on the bottom. The writing process may use the current pulse to generating a single Skyrmion, and the reading process may achieve by the topological hall effect. A current comes from the left or right will move the whole Skyrmion array so that we can read different part of the array.
Figure 4.5: Domain wall racetrack memory.[5]

Figure 4.6: Skyrmion-based racetrack memory.
Chapter 5

Conclusion

5.1 Summary

We developed a simulation tool that have the capability to simulate Skyrmion dynamics at finite temperature. Skyrmion dynamics are simulated by micromagnetic simulations. The Skyrmion-magnon scattering are shown by micromagnetic simulations. The scattering angle is strongly depend on the size of Skyrmion. A topological hall effect is shown to be a method to read a Skyrmion. Based on these simulations, a Skyrmion-based device is proposed.

5.2 Future Plans

Micromagnetic simulations is expected to do for the specific structure we proposed. We will continue finding new methods to reduce the energy needed to create a single Skyrmion based on our code. Also, the inner physics of magnon-Skyrmion scattering and Skyrmion creation process will be studied in the future since it’s important to understand these physics before build real devices. Some other architectures may be
proposed and simulated based on the spin wave dynamics, it’s possible to build logic circuit based on the spin wave structure. New code that combines the first principle may be developed to calculate the exchange constant and DM constant of different materials. We also plan to extend our code capability to simulate some 3D models, by using a 3D model we could simulate more complicated Skyrmion Lattice and Skyrmion-based devices.
Bibliography


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